52. (Amended) The method of claim 51 wherein the [chlorine] fluorine is provided in the gate oxide layer to a concentration of from about 1 x 10^{19} atoms/cm³ to about 1 x 10^{21} atoms/cm³.

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53. (Amended) The method of claim 51 wherein the gate comprises opposing lateral edges and a central region therebetween, the [chlorine] fluorine being provided within the gate oxide layer to a greater concentration proximate at least one of the gate edges than in the central region.